

T495T686K004ATE1K5

T495, Tantalum, MnO2 Tantalum, 68 uF, 10%, 4 VDC, SMD, MnO2, Molded, Low Profile, Low ESR, 1.5 Ohms, 3528, Height Max = 1.2mm

CATHODE (-) END VIEW SIDE VIEW ANODE (+) END VIEW BOTTOM VIEW BOTTOM VIEW

Click	here	for	the	3D	model.

Dimensions	
Footprint	3528
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
Н	1.1mm +/-0.1mm
Т	0.13mm REF
S	0.8mm +0.1/-0.3mm
F	2.2mm +/-0.1mm
Α	1.9mm MIN
E	2.2mm REF
G	1.8mm REF
X	0.05mm REF

Packaging Specifications				
Packaging	T&R, 178mm			
Packaging Quantity	3000			

General Information	
Series	T495
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low Profile, Low ESR
Features	Low ESR
RoHS	Yes
Termination	Tin
AEC-Q200	No
Component Weight	63.89 mg
Shelf Life	156 Weeks
MSL	1

Specifications	
Capacitance	68 uF
Capacitance Tolerance	10%
Voltage DC	4 VDC (85C), 2.68 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	20% 120Hz 25C
Failure Rate	N/A
Resistance	1500 mOhms (100kHz 25C)
Ripple Current	216 mA (rms, 100kHz 25C), 194.4 mA (rms, 85C), 86.4 mA (rms, 125C)
Leakage Current	2.7 uA (5min 25°C)

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